

New Jersey Semi-Conductor Products, Inc.

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SCHOTTKY RECTIFIER

160 Amp

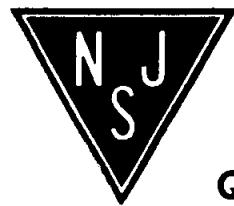
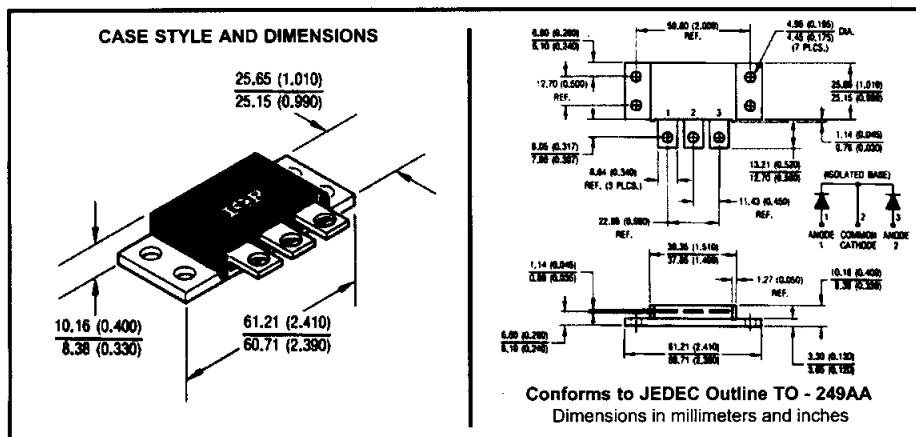
Major Ratings and Characteristics

Characteristics	162CMQ030	Units
$I_{F(AV)}$ Rectangular waveform	160	A
V_{RMM}	30	V
I_{FSM} @ tp = 5 μ s sine	7900	A
V_F @ 80 Apk, T_J = 125°C (per leg)	0.46	V
T_J range	-55 to 150	°C

Description/Features

The 162CMQ030 isolated, center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150 °C T_j operation
 - Isolated heatsink
 - Center tap module
 - High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 - Very low forward voltage drop
 - High frequency operation
 - Guard ring for enhanced ruggedness and long term reliability
 - Low profile, high current package



Quality Semi-Conductors

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Voltage Ratings

Part number	162CMQ030		
V_R Max. DC Reverse Voltage (V)			
V_{RWM} Max. Working Peak Reverse Voltage (V)	30		

Absolute Maximum Ratings

Parameters	162CMQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	160	A	50% duty cycle @ $T_c = 83^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg) * See Fig. 7	7900	A	5μs Sine or 3μs Rect. pulse
	980		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy (Per Leg)	72	mJ	$T_j = 25^\circ\text{C}$, $I_{AS} = 16\text{Amps}$, $L = 0.56\text{ mH}$
I_{AR} Repetitive Avalanche Current (Per Leg)	16	A	Current decaying linearly to zero in 1μsec Frequency limited by T_j max. $V_A = 1.5 \times V_R$ typical

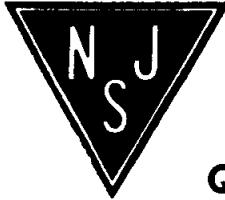
Electrical Specifications

Parameters	162CMQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.53	V	@ 80A
	0.65	V	@ 160A
	0.46	V	@ 80A
	0.63	V	@ 160A
I_{RM} Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	5	mA	$T_j = 25^\circ\text{C}$
	280	mA	$T_j = 125^\circ\text{C}$
C_T Max. Junction Capacitance (Per Leg)	3700	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_s Typical Series Inductance (Per Leg)	8.0	nH	Measured from terminal hole to terminal hole
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs	

(1) Pulse Width < 300μs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	162CMQ	Units	Conditions
T_j Max. Junction Temperature Range	-55 to 150	°C	
T_{stg} Max. Storage Temperature Range	-55 to 150	°C	
R_{thJC} Max. Thermal Resistance Junction to Case (Per Leg)	1.0	°C/W	DC operation * See Fig. 4
R_{thJC} Max. Thermal Resistance Junction to Case (Per Package)	0.50	°C/W	DC operation
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.10	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	58 (2.0)	g (oz.)	
T Mounting Torque	Min.	40(35)	Kg-cm
	Max.	58(50)	(lbf-in)
Case Style	TO - 249AA		JEDEC



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